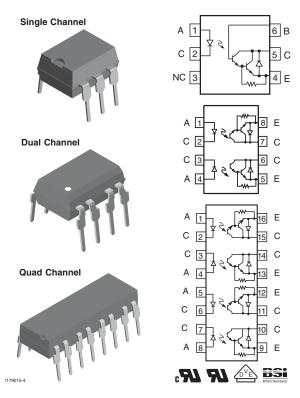


Optocoupler, Photodarlington Outtput, with Internal RBE (Single, Dual, Quad Channel)



FEATURES

- · Internal RBE for high stability
- Four available CTR categories per package type
- BV_{CEO} > 60 V
- Standard DIP packages
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





ROHS

ILQ66-4X009T

≥ 500

ILQ66-4X001

DESCRIPTION

IL66, ILD66, and ILQ66 are optically coupled isolators employing gallium arsenide infrared emitters and silicon photodarlington detectors. Switching can be accomplished while maintaining a high degree of isolation between driving and load circuits, with no crosstalk between channels.

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending available with option 1
- BSI IEC 60950; IEC 60065

ORDERING INFORMATION										
PART NU x = D (Dual) o	# X 0 # # CTR PACKAGE OPTION BIN			TAPE AND REEL	7.62 mm Option 7	Option 6 10.16 mm Option 9 > 0.1 mm				
	SINGLE (CHANNEL	DUAL CHANNEL			QUAD	QUAD CHANNEL			
AGENCY CERTIFIED/PACKAGE	CTR (%)									
OLITHI ILB/I AGIGAGE	2 mA					0.7 mA	2 mA			
UL, cUL, BSI	≥ 100	≥ 300	≥ 300	≥ 500	≥ 100	≥ 300	≥ 400	≥ 500		
DIP-4	IL66-1	IL66-2	-	-	-	-	-	-		
DIP-8	-	-	ILD66-2	ILD66-4	-	-	-	-		
SMD-8, option 7	-	-	-	ILD66-4X007T	-	-	-	-		
SMD-8, option 9	-	-	-	ILD66-4X009	_	-	-	-		
DIP-16	-	-	-	-	ILQ66-1	ILQ66-2	ILQ66-3	ILQ66-4		
SMD-16, option 7	-	-	-	-	-	-	-	ILQ66-4X007T		

Note

DIP-16

SMD-16, option 9

VDE, UL, cUL, BSI

DIP-4, 400 mil, option 6 | IL66-1X016

Additional optiony may be possible, please contact sales office.

≥ 100

≥ 300

≥ 300

≥ 500

≥ 100

≥ 300

≥ 400



PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT	<u> </u>				
Peak reverse voltage			V_{RM}	6.0	V
Forward continuous current			I _F	60	mA
Power dissipation			P _{diss}	100	mW
Derate linearly from 25 °C				1.33	mW/°C
OUTPUT	<u>.</u>				
Power dissipation			P _{diss}	150	mW
Derate from 25 °C				2.0	mW/°C
COUPLER	<u>.</u>				
Isolation test voltage	t = 1.0 s		V _{ISO}	5300	V _{RMS}
		IL66	P _{tot}	250	mW
Total package power dissipation		ILD66	P _{tot}	400	mW
		ILQ66	P _{tot}	500	mW
		IL66		3.3	mW/°C
Derate linearly from 25 °C		ILD66		5.33	mW/°C
		ILQ66		6.67	mW/°C
Creepage distance				≥ 7.0	mm
Clearance distance				≥ 7.0	mm
Comparative tracking index			CTI	175	
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}$		R _{IO}	≥ 10 ¹²	Ω
ISOIALIOTI (ESISTATICE	V _{IO} = 500 V, T _{amb} = 100 °C		R _{IO}	≥ 10 ¹¹	Ω
Storage temperature			T _{stg}	- 55 to + 125	°C
Operating temperature			T _{amb}	- 55 to + 100	°C
Lead soldering time at 260 °C				10	S

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I _F = 20 mA	V_{F}		1.25	1.5	V		
Reverse current	$V_{R} = 6.0 \text{ V}$	I _R		0.1	10	μΑ		
Capacitance	V _R = 0 V	Co		25		pF		
OUTPUT								
Collector emitter breakdown voltage	$I_C = 1.0 \text{ mA}, I_F = 0 \text{ A}$	BV _{CEO}	60			V		
Collector base breakdown voltage (IL66)	I _C = 10 μA	BV _{CBO}	60			V		
Collector emitter leakage current	$V_{CE} = 50 \text{ V}, I_F = 0 \text{ A}$	I _{CEO}		1.0	100	nA		
Capacitance collector emitter	V _{CE} = 10 V			3.4		pF		
COUPLER								
Saturation voltage, collector emitter	$I_C = 10 \text{ mA}, I_F = 10 \text{ mA}$	V _{CEsat}		0.9	1.0	V		

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_F = 2.0 \text{ mA}, V_{CE} = 10 \text{ V}$ $I_F = 0.7 \text{ mA}, V_{CE} = 10 \text{ V}$	IL(D,Q)66-1	CTR	100	400		%
		IL(D,Q)66-2	CTR	300	500		%
		IL(D,Q)66-3	CTR	400	500		%
	$I_F = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	IL(D,Q)66-4	CTR	500	750		%

SWITCHING CHARACTERSITICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
NON SATURATED							
Rise time -1, -2, -4	V_{CC} = 10 V, I_F = 2.0 mA, R_L = 100 Ω	t _r			200	μs	
Fall time -1, -2, -4	V_{CC} = 10 V, I_F = 2.0 mA, R_L = 100 Ω	t _f			200	μs	
Rise time -3	V_{CC} = 10 V, I_F = 0.7 mA, R_L = 100 Ω	t _r			200	μs	
Fall time -3	V_{CC} = 10 V, I_F = 0.7 mA, R_L = 100 Ω	t _f			200	μs	

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

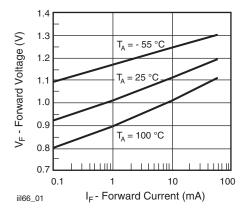


Fig. 1 - Forward Voltage vs. Forward Current

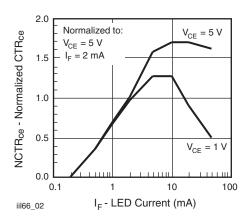


Fig. 2 - Normalized Non-Saturated and Saturated CTR $_{\rm CE}$ vs. LED Current

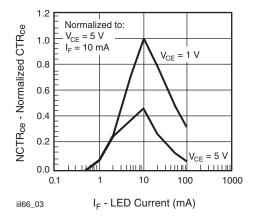


Fig. 3 - Normalized Non-Saturated and Saturated CTR_{CE} vs. LED Current

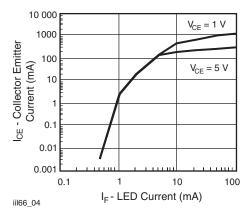


Fig. 4 - Non-Saturated and Saturated Collector Emitter Current vs. LED Current

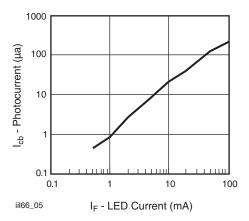


Fig. 5 - Collector Base Photocurrent vs. LED Current

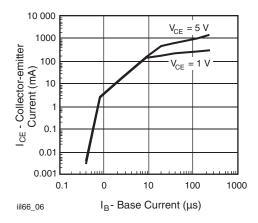


Fig. 6 - Collector Emitter Current vs. LED Current

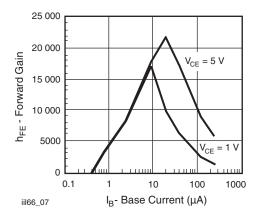


Fig. 7 - Non-Saturated and Saturated h_{FE} vs. LED Current

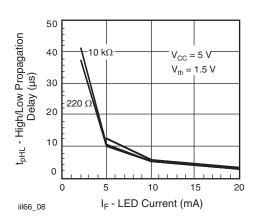


Fig. 8 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current

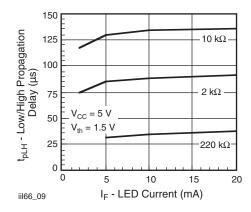


Fig. 9 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

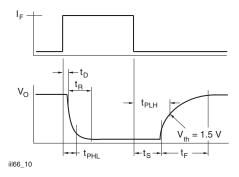


Fig. 10 - Switching Waveform



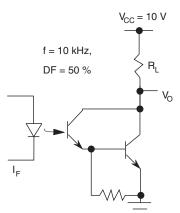
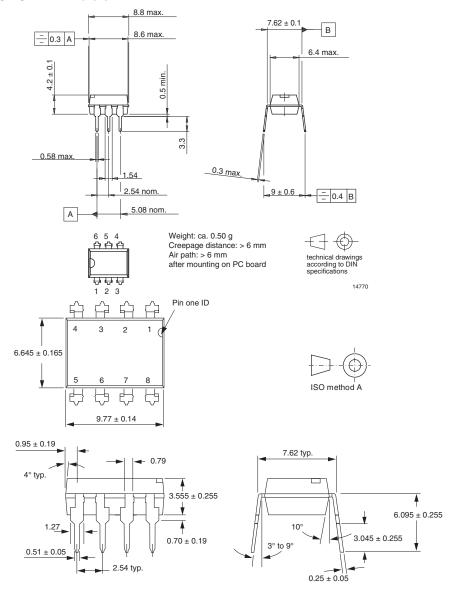
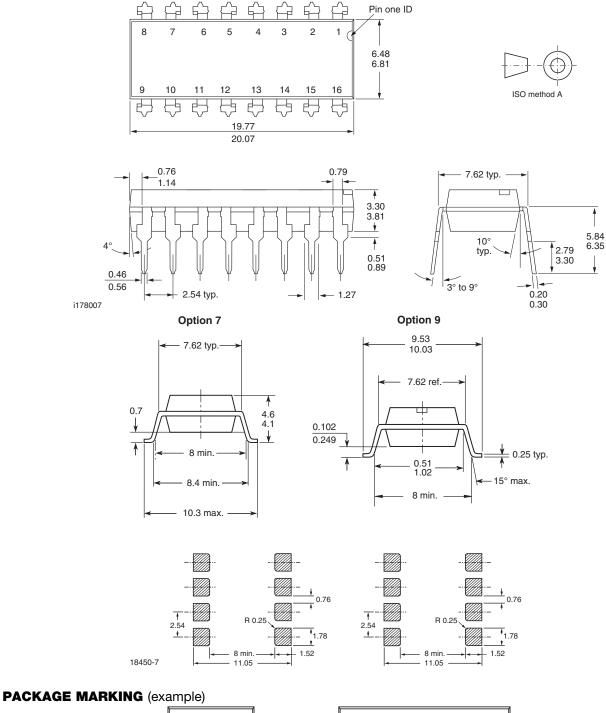


Fig. 11 - Switching Schematic

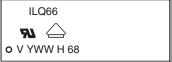
PACKAGE DIMENSIONS in millimeters











Notes

- Only options 1 and 7 reflected in the package marking
- The VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking



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Vishay

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